

Features

- Dual N-Channel MOSFET
- Low On-Resistance
- Very Low Gate Threshold Voltage, 1.2V max
- Low Input Capacitance
- Fast Switching Speed
- Low Input/Output Leakage
- Ultra-Small Surface Mount Package
- ESD Protected Gate
- **Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)**
- **Halogen and Antimony Free. "Green" Device (Note 3)**

Mechanical Data

- Case: SOT563
- Case Material: Molded Plastic, "Green" Molding Compound.
- UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Connections: See Diagram
- Terminals: Finish – Matte Tin Annealed over Copper Leadframe.
- Solderable per MIL-STD-202, Method 208 (E3)
- Weight: 0.006 grams (Approximate)



Ordering Information (Note 4)

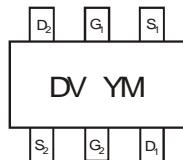
Part Number	Case	Packaging
DMN32D2LV-7	SOT563	3,000/Tape & Reel

Notes:

1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
2. See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
4. For packaging details, go to our website at <http://www.diodes.com/products/packages.html>

Marking Information

SOT563



DV = Product Type Marking Code
YM = Date Code Marking
Y = Year (ex: U = 2007)
M = Month (ex: 9 = September)

Date Code Key

Year	2007	---	2014	2015	2016	2017	2018	2019	2020	2021		
Code	U	---	B	C	D	E	F	G	H	I		
Month	Jan	Feb	Mar	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	O	N	D

Maximum Ratings (@ $T_A = +25^\circ\text{C}$, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Drain Source Voltage	V_{DSS}	30	V
Gate-Source Voltage	V_{GSS}	± 10	V
Drain Current (Note 5)	I_D	400	mA

Thermal Characteristics

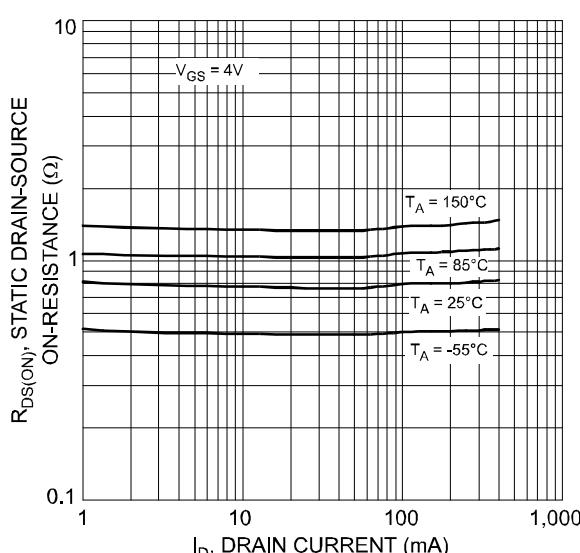
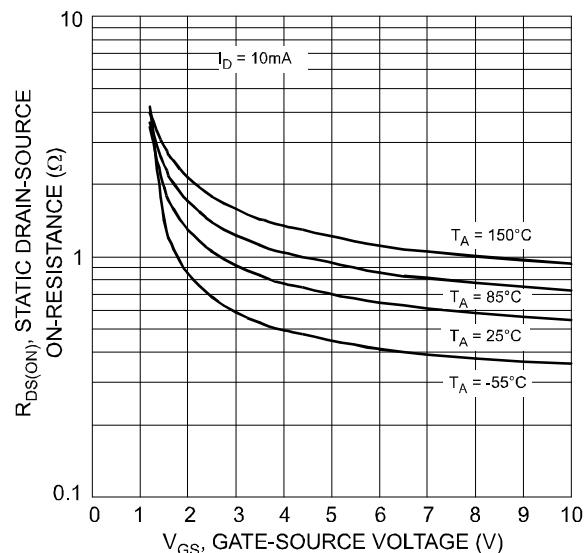
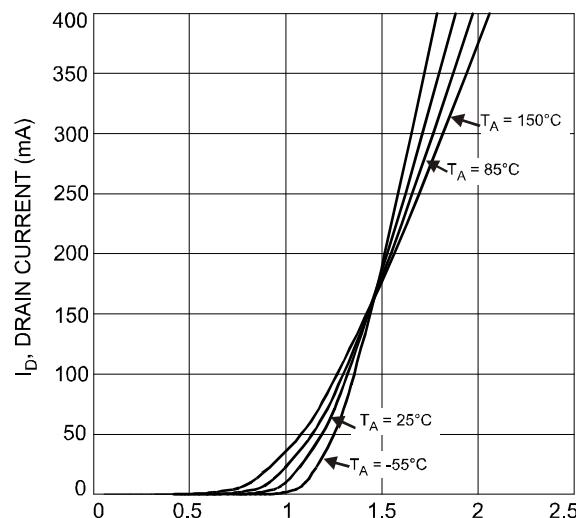
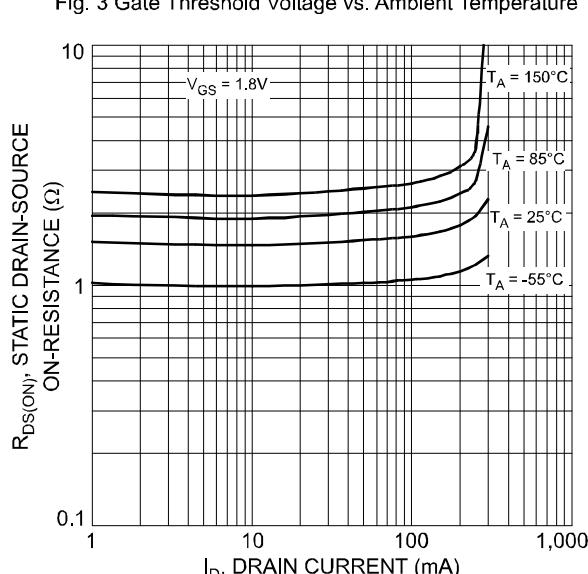
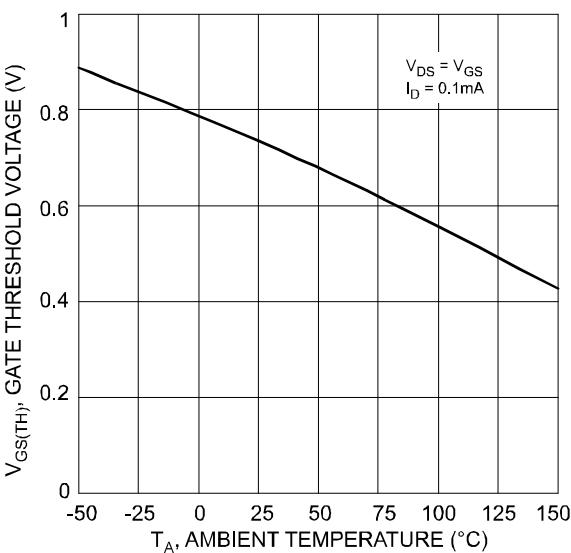
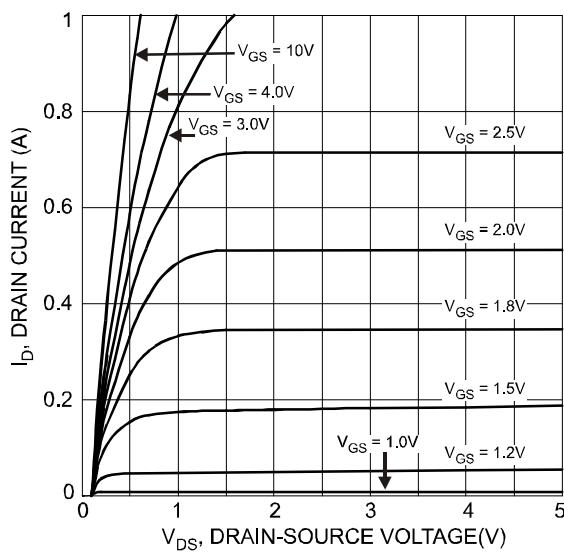
Total Power Dissipation (Note 5)	P_D	450	mW
Thermal Resistance, Junction to Ambient (Note 5)	$R_{\theta JA}$	313	°C/W
Operating and Storage Temperature Range	T_J, T_{STG}	-55 to +150	°C

Electrical Characteristics (@ $T_A = +25^\circ\text{C}$, unless otherwise specified.)

Characteristic	Symbol	Min	Typ	Max	Unit	Test Condition
OFF CHARACTERISTICS (Note 6)						
Drain-Source Breakdown Voltage	BV_{DSS}	30	—	—	V	$V_{GS} = 0\text{V}, I_D = 250\mu\text{A}$
Zero Gate Voltage Drain Current @ $T_J = +25^\circ\text{C}$	I_{DSS}	—	—	1	μA	$V_{DS} = 30\text{V}, V_{GS} = 0\text{V}$
Gate-Body Leakage @ $T_J = +25^\circ\text{C}$	I_{GSS}	—	—	± 10 ± 500 ± 1	μA nA nA	$V_{GS} = \pm 10\text{V}, V_{DS} = 0\text{V}$ $V_{GS} = \pm 5\text{V}, V_{DS} = 0\text{V}$ $V_{GS} = \pm 2.5\text{V}, V_{DS} = 0\text{V}$
Gate-Body Leakage (Note 7) @ $T_J = +105^\circ\text{C}$ @ $T_J = +125^\circ\text{C}$	I_{GSS}	—	± 8 ± 15	± 100 ± 100	nA nA	$V_{GS} = \pm 2.5\text{V}, V_{DS} = 0\text{V}$
ON CHARACTERISTICS (Note 6)						
Gate Threshold Voltage	$V_{GS(TH)}$	0.6	—	1.2	V	$V_{DS} = V_{GS}, I_D = 250\mu\text{A}$
Static Drain-Source On-Resistance	$R_{DS(ON)}$	—	—	2.2 1.5 1.2	Ω	$V_{GS} = 1.8\text{V}, I_D = 20\text{mA}$ $V_{GS} = 2.5\text{V}, I_D = 20\text{mA}$ $V_{GS} = 4.0\text{V}, I_D = 100\text{mA}$
Forward Transconductance	$ Y_{FS} $	100	—	—	mS	$V_{DS} = 10\text{V}, I_D = 0.1\text{A}$
Source-Drain Diode Forward Voltage	V_{SD}	0.5	—	1.4	V	$V_{GS} = 0\text{V}, I_S = 115\text{mA}$
DYNAMIC CHARACTERISTICS (Note 7)						
Input Capacitance	C_{iss}	—	39	—	pF	$V_{DS} = 3\text{V}, V_{GS} = 0\text{V}$ $f = 1.0\text{MHz}$
Output Capacitance	C_{oss}	—	10	—	pF	
Reverse Transfer Capacitance	C_{rss}	—	3.6	—	pF	
Switching Time	Turn-On Time	t_{ON}	—	11	—	ns
	Turn-Off Time	t_{OFF}	—	51	—	ns
$V_{DD} = 5\text{V}, I_D = 10\text{ mA}, V_{GS} = 5\text{V}$						

Notes:

5. Device mounted on FR-4 PCB, 1 inch x 0.85 inch x 0.062 inch; pad layout as shown on Diodes Inc. suggested pad layout document AP02001, which can be found at <http://www.diodes.com/datasheets/ap02001.pdf>.
6. Short duration pulse test used to minimize self-heating effect.
7. Guaranteed by design. Not subject to production testing.



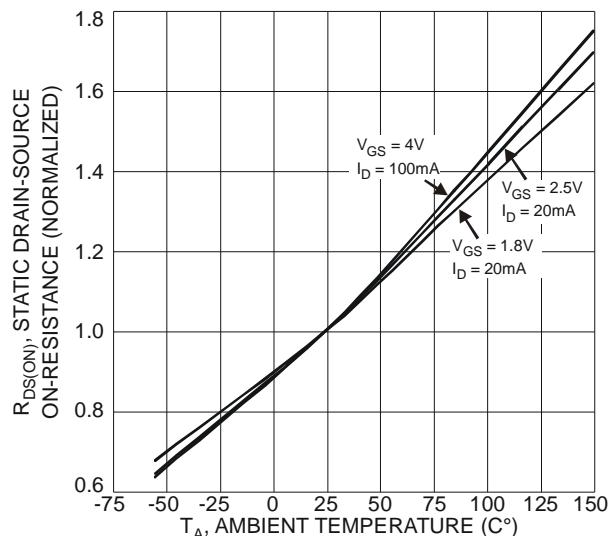


Fig. 7 Normalized Static Drain-Source On-Resistance vs. Ambient Temperature

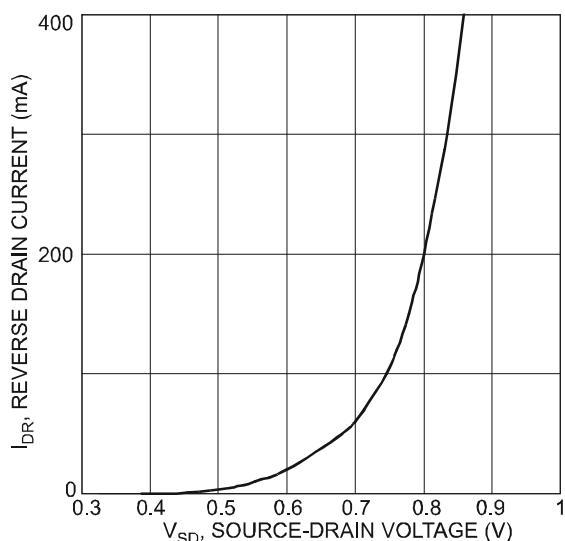


Fig. 8 Reverse Drain Current vs. Source-Drain Voltage

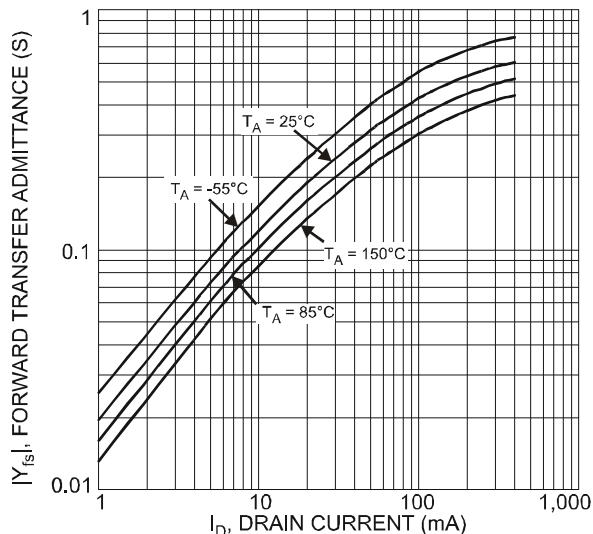


Fig. 9 Forward Transfer Admittance vs. Drain Current

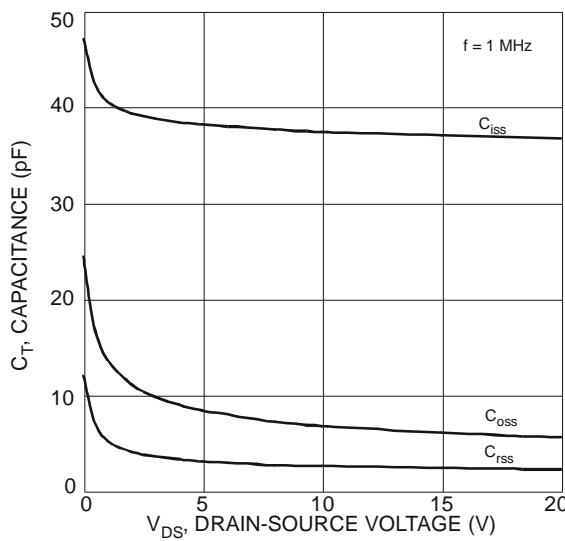


Fig. 10 Typical Capacitance

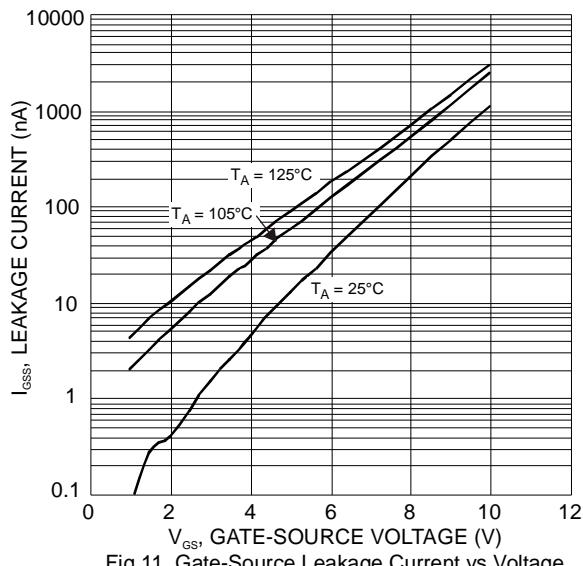


Fig. 11 Gate-Source Leakage Current vs Voltage

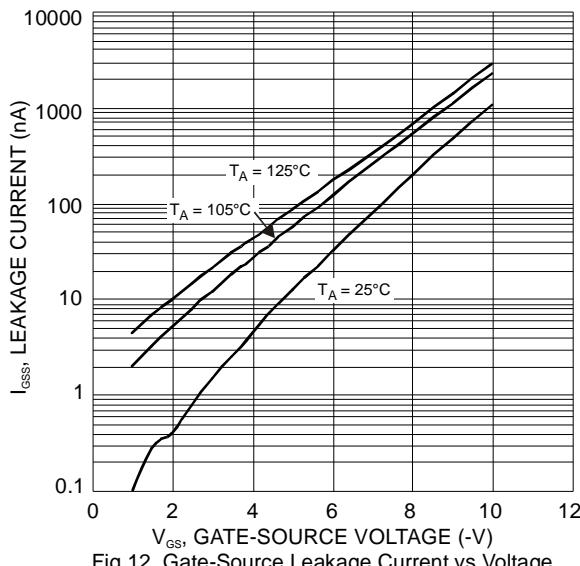
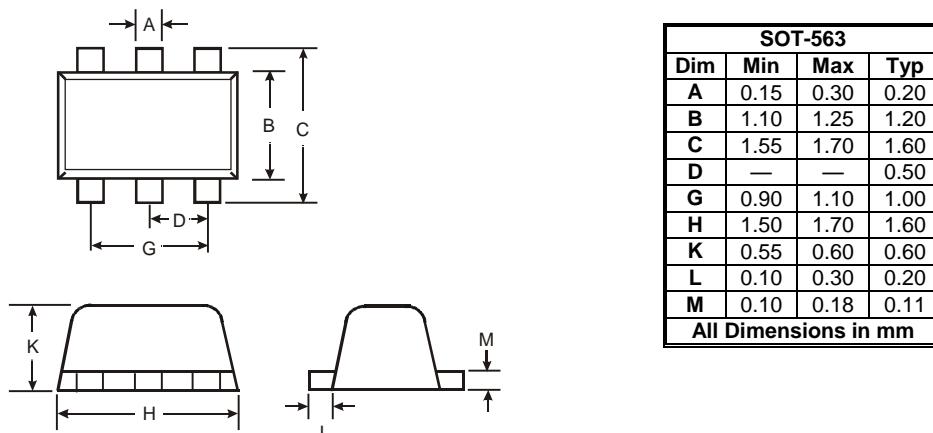


Fig. 12 Gate-Source Leakage Current vs Voltage

Package Outline Dimensions

Please see AP02002 at <http://www.diodes.com/datasheets/ap02002.pdf> for the latest version.

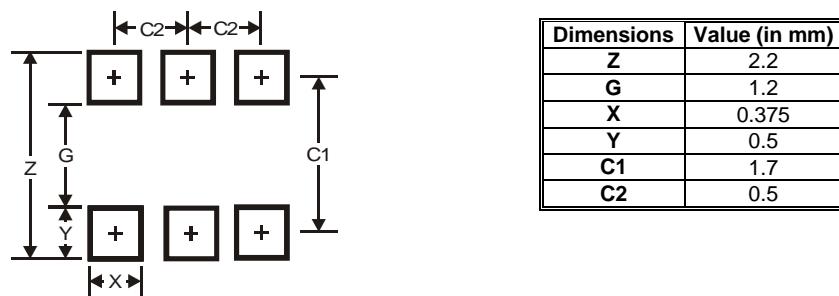
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Suggested Pad Layout

Please see AP02001 at <http://www.diodes.com/datasheets/ap02001.pdf> for the latest version.

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